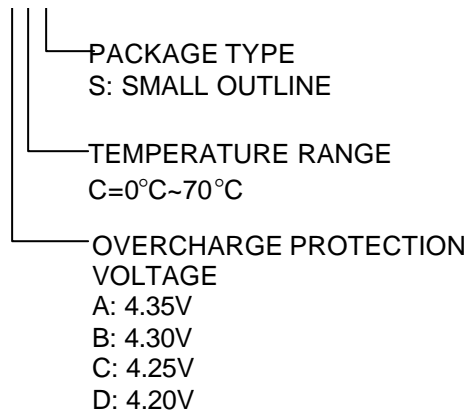




## ORDERING INFORMATION

AIC1803 XXX

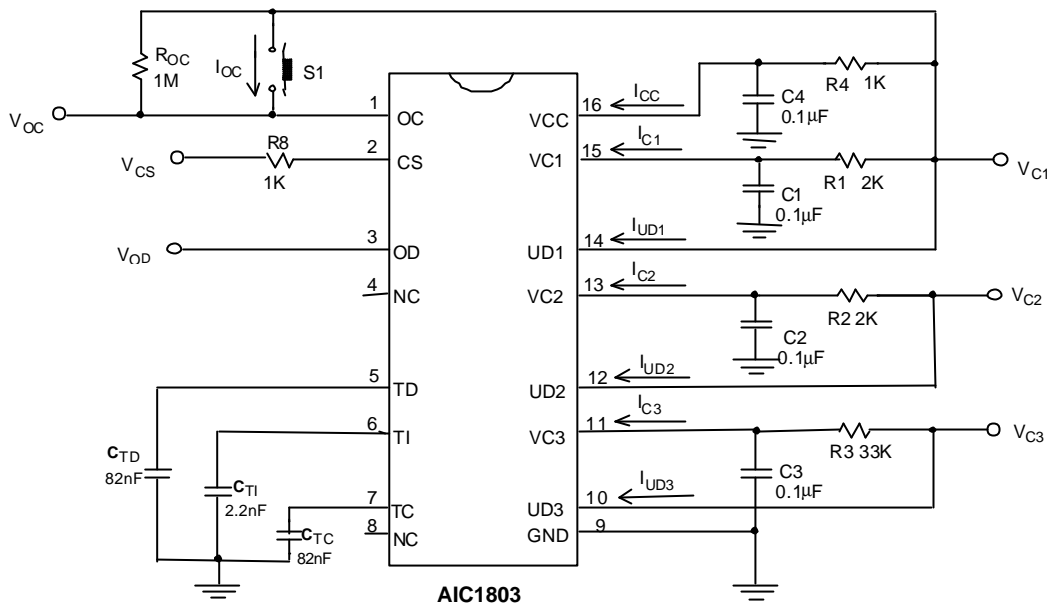


ORDER NUMBER	PIN CONFIGURATION
AIC1803ACS AIC1803BCS AIC1803CCS AIC1803DCS (PLASTIC SO)	TOP VIEW
	OC [1] [16] VCC
	CS [2] [15] VC1
	OD [3] [14] UD1
	NC [4] [13] VC2
	TD [5] [12] UD2
	TI [6] [11] VC3
	TC [7] [10] UD3
NC [8] [9] GND	

## ABSOLUTE MAXIMUM RATINGS

Supply Voltage .....	18V
DC Voltage Applied on other Pins .....	18V
Operating Temperature Range.....	-20°C~70°C
Storage Temperature Range .....	- 65°C ~125°C

## TEST CIRCUIT



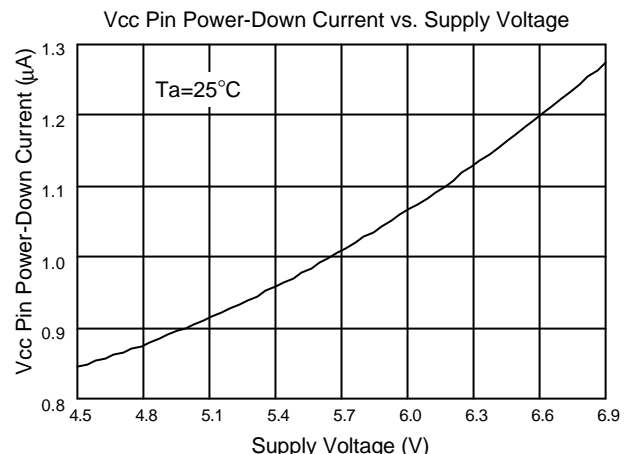
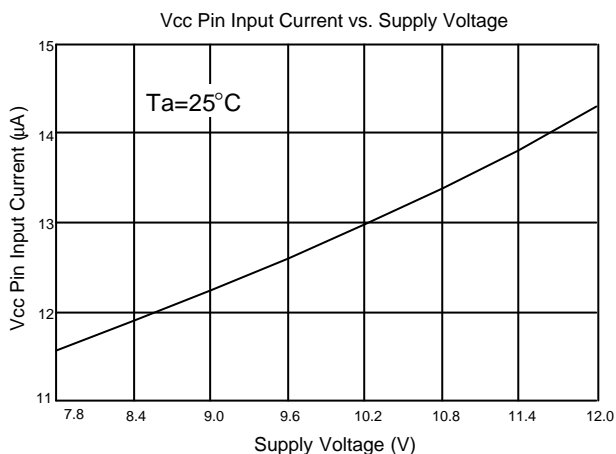
**ELECTRICAL CHARACTERISTICS** (Ta=25°C, unless otherwise specified.)

PARAMETER	TEST CONDITIONS	SYMBOL	MIN.	TYP.	MAX.	UNIT
VCC Pin Input Current in Normal Mode	V <sub>CELL</sub> =3.5V	I <sub>CC</sub>		13	20	μA
VC1 Pin Input Current in Normal Mode	V <sub>CELL</sub> =3.5V	I <sub>C1</sub>		0.4	1.0	μA
VC2 Pin Input Current in Normal Mode	V <sub>CELL</sub> =3.5V	I <sub>C2</sub>		0.4	1.0	μA
VC3 Pin Input Current in Normal Mode	V <sub>CELL</sub> =3.5V	I <sub>C3</sub>		0.2	0.5	μA
Vcc Pin Input Current in Power-Down Mode	V <sub>CELL</sub> =2.3V	I <sub>CC(PD)</sub>		1.3	2	μA
VC1,VC2,VC3 Input Current in Power-Down Mode	V <sub>CELL</sub> =2.3V	I <sub>C(PD)</sub>		0.01	0.15	μA
Overcharge Protection Voltage	AIC1803A	V <sub>OCP</sub>	4.32	4.35	4.38	V
	AIC1803B		4.27	4.30	4.33	
	AIC1803C		4.22	4.25	4.28	
	AIC1803D		4.17	4.20	4.23	
Overcharge Hysteresis Voltage		V <sub>HYS</sub>	150	200	250	mV
Overdischarge Protection Voltage		V <sub>ODP</sub>	2.27	2.40	2.53	V
Overdischarge Release Voltage		V <sub>ODR</sub>	2.85	3.00	3.15	V
Overcurrent Protection Voltage	V <sub>CELL</sub> =3.5V	V <sub>OIP</sub>	135	150	165	mV
Overcharge Delay Time	V <sub>CELL1</sub> =V <sub>OCP</sub> -30mV→V <sub>OCP</sub> +30mV V <sub>CELL2</sub> =V <sub>CELL3</sub> =3.5V, C <sub>TC</sub> =1nF	T <sub>OC</sub>	10	21	32	mS
Overdischarge Delay Time	V <sub>CELL1</sub> =2.5V→2.3V V <sub>CELL2</sub> =V <sub>CELL3</sub> =3.5V, C <sub>TD</sub> =1nF	T <sub>OD</sub>	10	21	32	mS
Overcurrent Delay Time (1)	V <sub>CELL</sub> =3.5V,0.15V<V <sub>CC</sub> -V <sub>CS</sub> <0.3V,C <sub>TI</sub> =2.2nF	T <sub>O11</sub>	7	15	23	mS

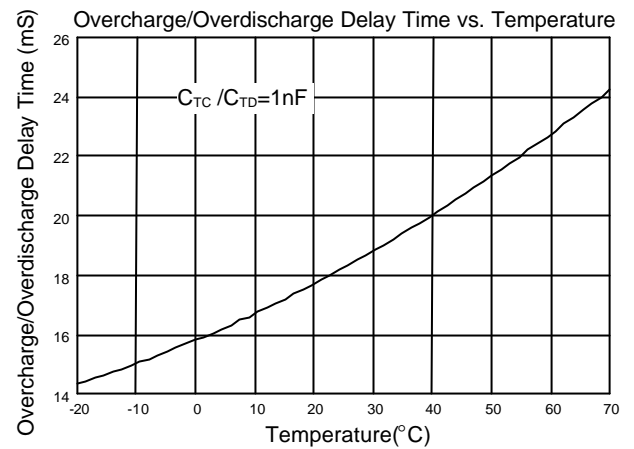
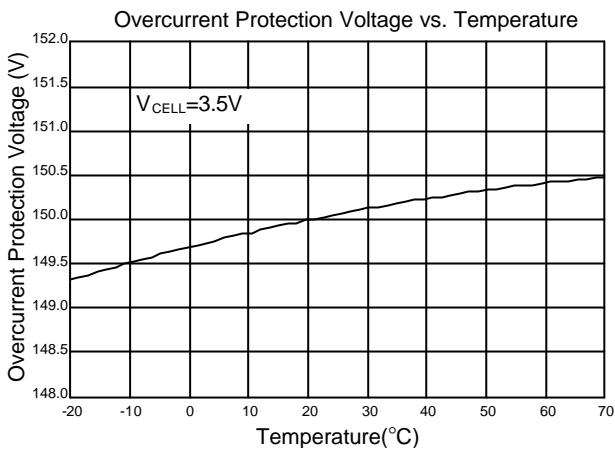
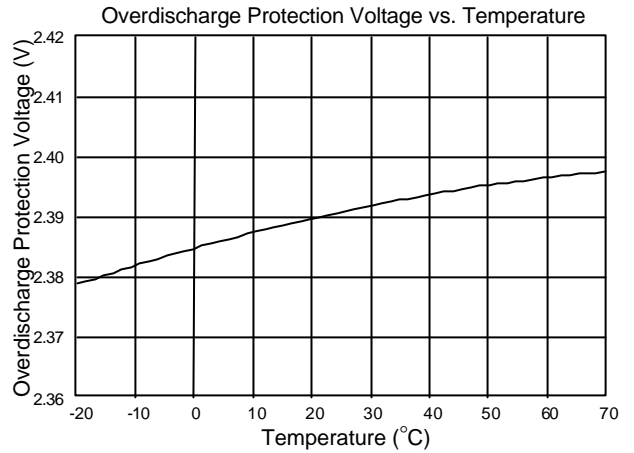
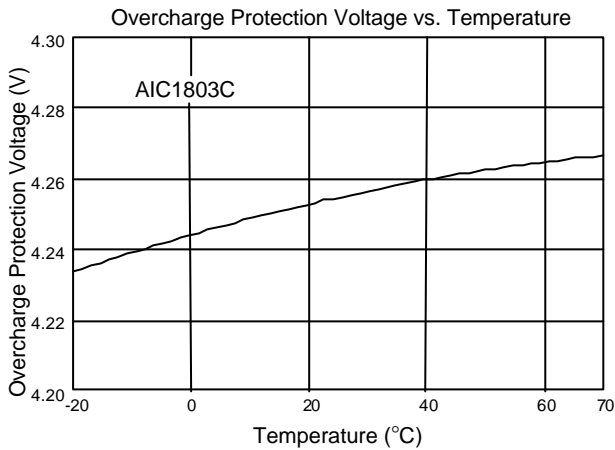
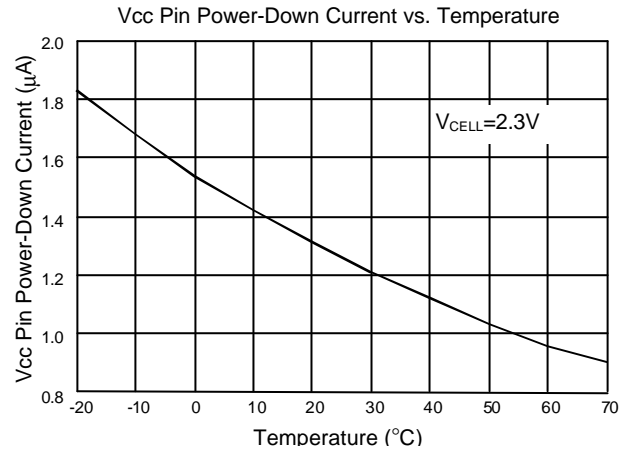
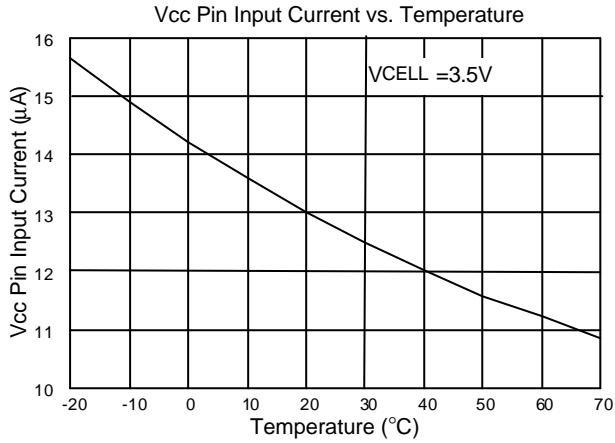
**ELECTRICAL CHARACTERISTICS** (Ta=25°C, unless otherwise specified.)

PARAMETER	TEST CONDITIONS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Overcurrent Delay Time (2)	$V_{CELL}=3.5V,$ $0.3V < V_{CC} - V_{CS} < 1.0V$	$T_{OI2}$	2	4	6	mS
Overcurrent Delay Time (3)	$V_{CELL}=3.5V, V_{CC}-$ $V_{CS} > 1.0V$	$T_{OI3}$	150	300	450	$\mu$ S
OC Pin Sink Current	$V_{CELL1}=4.4V,$ $V_{CELL2} = V_{CELL3}=3.5V,$ OC Pin Short to $V_{CC}$	$I_{OC}$	2.0	2.8	3.6	mA
OD Pin Output "H" Voltage		$V_{DH}$	$V_{CC}-0.15V$		$V_{CC}-0.03V$	V
OD Pin Output "L" Voltage		$V_{DL}$		0.01	0.15	V
Charge Detection Threshold Voltage	$V_{CELL}=2.3V$	$V_{CH}$		$V_{CC}+0.4$	$V_{CC}+0.55$	V
UD1 Pin Cell-Balancing Bleeding Current	$V_{CELL1}=4.4V,$ $V_{CELL2} = V_{CELL3}=3.5V$	$I_{UD1}$	5.9	8.4	10.9	mA
UD2 Pin Cell-Balancing Bleeding Current	$V_{CELL2}=4.4V,$ $V_{CELL1} = V_{CELL3}=3.5V$	$I_{UD2}$	6.1	8.7	11.3	mA
UD3 Pin Cell-Balancing Bleeding Current	$V_{CELL3}=4.4V,$ $V_{CELL1} = V_{CELL2}=3.5V$	$I_{UD3}$	6.4	9.2	12.0	mA

Note:  $V_{CELL}$  means the battery cell voltage. Therefore,  
 $V_{CELL1} = V_{C1} - V_{C2}$   
 $V_{CELL2} = V_{C2} - V_{C3}$   
 $V_{CELL3} = V_{C3}$

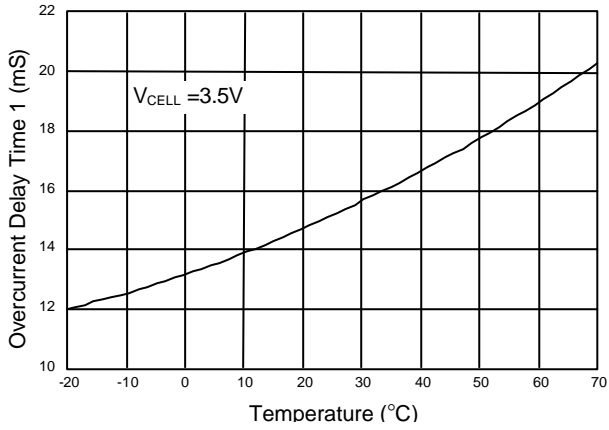
**TYPICAL PERFORMANCE CHARACTERISTICS**


## TYPICAL PERFORMANCE CHARACTERISTICS (CONTINUED)

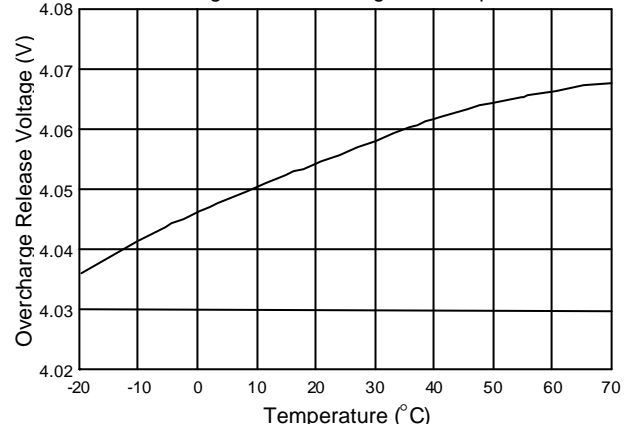


**TYPICAL PERFORMANCE CHARACTERISTICS (CONTINUED)**

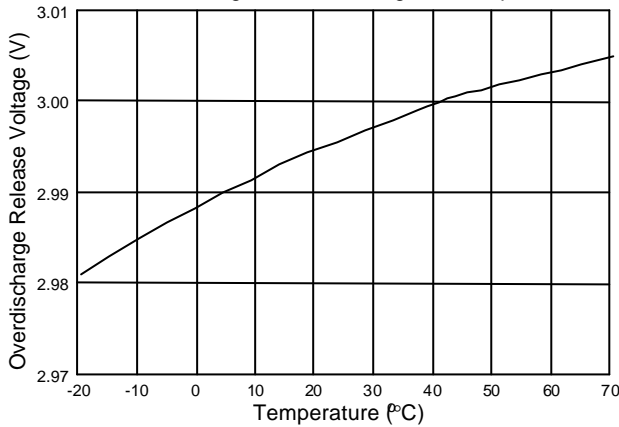
Overcurrent Delay Time 1 vs. Temperature



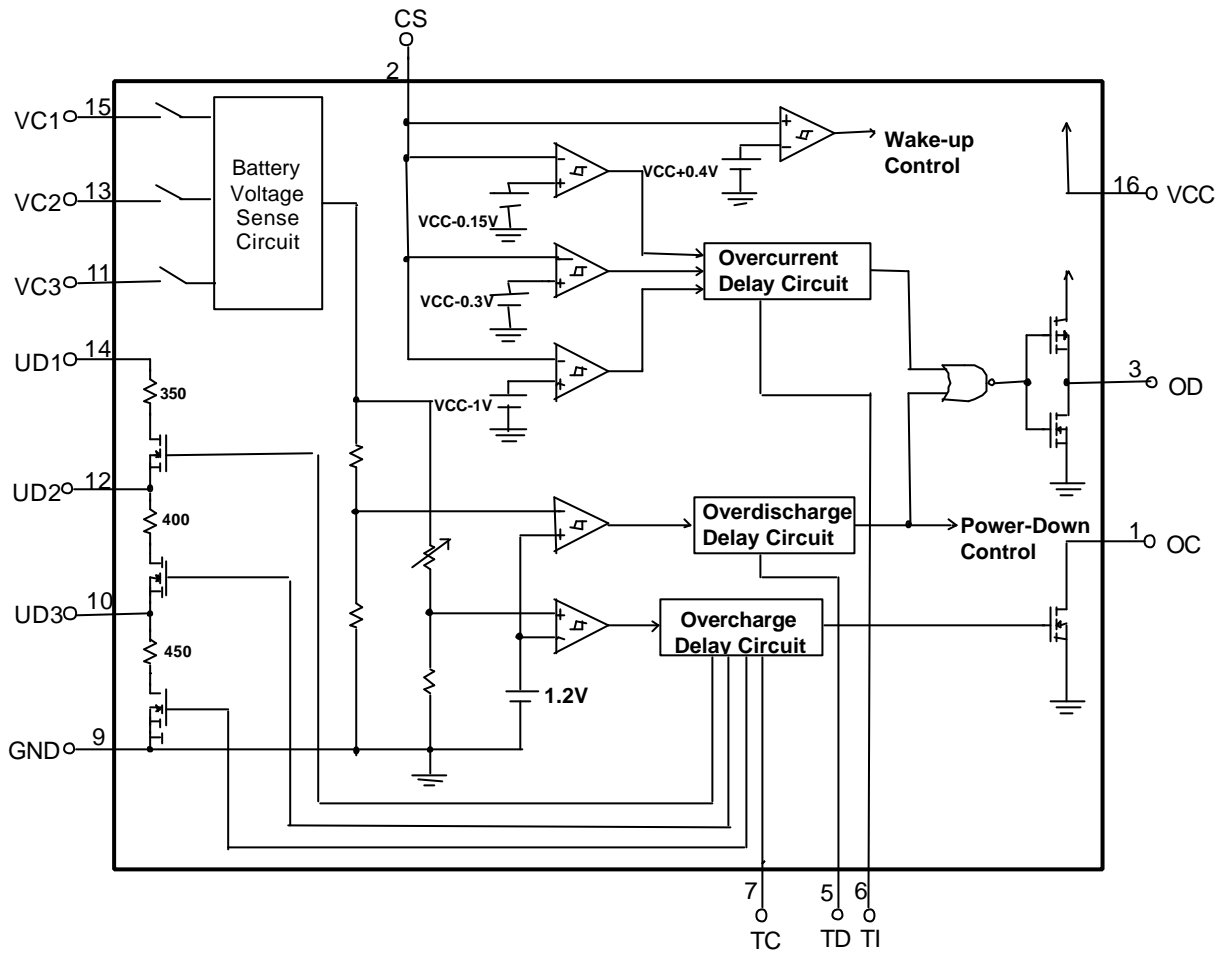
Overcharge Release Voltage vs. Temperature



Overdischarge Release Voltage vs. Temperature



■ BLOCK DIAGRAM



## ■ PIN DESCRIPTIONS

<p>PIN 1: OC- NMOS open drain output for control of the charge control MOSFET M2. When overcharge occurs, this pin sinks current to switch the external PNP Q1 on, and charging is inhibited by turning off the charge control MOSFET M2.</p> <p>PIN 2: CS- Input pin for current sensing. Using the drain-source voltage of the discharge control MOSFET M1 (voltage between VCC and CS), it senses discharge current during normal mode and detects whether charging current is present during power-down mode.</p> <p>PIN 3: OD - Output pin for control of discharge control MOSFET M1.</p> <p>PIN 4: NC - No connection</p> <p>PIN 5: TD- Overdischarge delay time setting pin.</p> <p>PIN 6: TI- Overcurrent delay time setting pin.</p> <p>PIN 7: TC - Overcharge delay time setting pin.</p> <p>PIN 8: NC- No connection.</p> <p>PIN 9: GND - Ground pin. This pin is to be</p>	<p>connected to the negative terminal of the battery cell BAT3.</p> <p>PIN10: UD3 - This pin is to be connected to the positive terminal of the battery cell BAT3 for cell-balancing bleeding function under overcharge condition.</p> <p>PIN11: VC3- Input pin for battery BAT3 voltage sensing. This pin is to be connected to the positive terminal of the battery cell BAT3.</p> <p>PIN12: UD2 - This pin is to be connected to the positive terminal of the battery cell BAT2 for cell-balancing bleeding function under overcharge condition.</p> <p>PIN13: VC2- Input pin for battery BAT2 voltage sensing. This pin is to be connected to the positive terminal of the battery cell BAT2.</p> <p>PIN14: UD1- This pin is to be connected to the positive terminal of the battery cell BAT2.</p> <p>PIN15: VC1- Input pin for battery BAT1 voltage sensing. This pin is to be connected to the positive terminal of the battery cell BAT1.</p> <p>PIN16: VCC - Power supply pin. This pin is to be connected to the positive terminal of the battery cell BAT1.</p>
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## ■ APPLICATION INFORMATIONS

### ● THE OPERATION

#### Initialization

On initial power-up, such as connecting the battery pack for the first time to the AIC1803, the AIC1803 enters the power-down mode. A charger must be applied to the AIC1803 circuit to enable the pack.

#### Overcharge Protection

When the voltage of either of the battery cells exceeds the overcharge protection voltage ( $V_{OCP}$ )

beyond the overcharge delay time ( $T_{OC}$ ) period, charging is inhibited by the turning-off of the charge control MOSFET M2. The overcharge delay time is set by the external capacitor  $C_{TC}$ . Inhibition of charging is immediately released when the voltage of the overcharged cell becomes lower than overcharge release voltage ( $V_{OCR}$  or  $V_{OCP}-V_{HYS}$ ) through discharging.

#### Overdischarge Protection

When the voltage of either of the battery cells falls below the overdischarge protection voltage ( $V_{ODP}$ )



beyond the overdischarge delay time ( $T_{OD}$ ) period, discharging is inhibited by the turning-off of the discharge control MOSFET M1. The overdischarge delay time is set by the external capacitor  $C_{TD}$ . Inhibition of discharging is immediately released when the voltage of the overdischarge cell becomes higher than the overdischarge release voltage ( $V_{ODR}$ ) through charging.

### Overcurrent Protection

In normal mode, the AIC1803 continuously monitors the discharge current by sensing the voltage of CS pin. If the voltage  $V_{CC}-V_{CS}$  exceeds the overcurrent protection voltage ( $V_{OIP}$ ) beyond the overcurrent delay time ( $T_{OI}$ ) period, the overcurrent protection circuit operates and discharging is inhibited by the turning-off of the discharge control MOSFET M1. Discharging must be inhibited for at least 256mS after overcurrent takes place to avoid damage to external control MOSFETs due to rapidly switching transient between BATT+ and BATT- terminals. The overcurrent condition returns to normal mode when the load is released and the impedance between the BATT+ and BATT- terminals is  $20M\Omega$  or higher.

The AIC1803 is provided with the three overcurrent detection levels (0.15V, 0.3V and 1.0V) and the three overcurrent delay time ( $T_{OI1}$ ,  $T_{OI2}$  and  $T_{OI3}$ ) corresponding to each overcurrent detection level.  $T_{OI1}$  is set by the external capacitor  $C_{TI}$ .  $T_{OI2}$  and  $T_{OI3}$  default to 4mS and 300 $\mu$ s respectively, and can not be adjusted due to protection of external MOSFETs

### Cell-Balancing Bleeding after Overcharge

When either of the battery cells is overcharged, the AIC1803 provides the cell-balancing bleeding function to discharge the overcharged cell at about 9mA until the voltage of the overcharged cell decreases to overcharge release voltage

( $V_{OCR}$  or  $V_{OCP}-V_{HYS}$ ). This function is accomplished by connecting UD1, UD2, UD3 pins to the positive terminals of battery cells BAT1, BAT2, BAT3 respectively. The bleeding current can be decreased by inserting resistors along UD1 pin to BAT1 positive terminal path and UD3 pin to BAT3 positive terminal path.

### Power-Down after Overdischarge

When overdischarge occurs, the AIC1803 will go into power-down mode, turning off all the timing generation and detection circuitry to reduce the quiescent current to about 1.3 $\mu$ A ( $V_{CC}=6.9V$ ). In the unusual case where one battery cell is overdischarged while another one under overcharge condition, the AIC1803 will turn off all the detection circuitry except the overcharge detection circuit for the cell under overcharge condition.

### Charge Detection after Overdischarge

When overdischarge occurs, the discharge control MOSFET M1 turns off and discharging is inhibited. However, charging is still permitted through the parasitic diode of M1. Once the charger is connected to the battery pack, the AIC1803 immediately turns on all the timing generation and detection circuitry and goes into normal mode. Charging is determined to be in progress if the CS pin voltage is higher than  $V_{CC} + 0.4V$  (charge detection threshold voltage  $V_{CH}$ ).

## • DESIGN GUIDE

### Setting the Overcharge and Overdischarge Delay Time

The overcharge delay time is set by the external capacitor  $C_{TC}$  and the overdischarge delay time is set by the external capacitor  $C_{TD}$ . The relationship between capacitance of the external capacitors and delay time is tabulated as below.

C <sub>TC</sub> , C <sub>TD</sub> (F)	1n	5n	10n	22n	33n
T <sub>OC</sub> , T <sub>OD</sub> (S)	21m	52m	132m	253m	347m

C <sub>TC</sub> , C <sub>TD</sub> (F)	47n	68n	82n	100n
T <sub>OC</sub> , T <sub>OD</sub> (S)	617m	748m	1004m	1630m

The delay time can also be approximately calculated by the following equations (if C<sub>TC</sub>, C<sub>TD</sub> ≤ 82nF) :

$$T_{OC}(mS) = 11.8 \times C_{TC}(nF)$$

$$T_{OD}(mS) = 11.8 \times C_{TD}(nF)$$

### Setting the Overcurrent Delay Time 1

The overcurrent delay time 1 (T<sub>O11</sub>) at 0.15V < V<sub>CC</sub>-V<sub>CS</sub> < 0.3V is set by the external capacitor C<sub>T1</sub>, while the overcurrent delay time 2 and 3 (T<sub>O12</sub> and T<sub>O13</sub>) is fixed by IC internal circuit. The relationship between capacitance of the external capacitor and delay time is tabulated as below.

C <sub>T1</sub> (F)	1n	2.2n	3.3n	5n	6.8n	10n
T <sub>O1</sub> (mS)	4.8	15.0	18.8	23.6	31.0	61.8

### Selection of External Control MOSFETs

Because the overcurrent protection voltage is preset, the threshold current for overcurrent detection is determined by the turn-on resistance of the discharge control MOSFET M1. The turn-on resistance of the external control MOSFETs can be determined by the equation: R<sub>ON</sub>=V<sub>OIP</sub>/I<sub>T</sub> (I<sub>T</sub> is the overcurrent threshold current). For example, if the overcurrent threshold current I<sub>T</sub> is designed to be 5A, the turn-on resistance of the external control MOSFETs must be 30mΩ. Users should

be aware that turn-on resistance of the MOSFET changes with temperature variation due to heat dissipation. It changes with the voltage between gate and source as well. (Turn-on resistance of a MOSFET increases as the voltage between gate and source decreases). Once the turn-on resistance of the external MOSFET changes, the overcurrent threshold current will change accordingly.

### Suppressing the Ripple and Disturbance from Charger

To suppress the ripple and disturbance from charger, connecting R1 to R4 and C1 to C4 is recommended.

### Controlling the Charge Control MOSFET

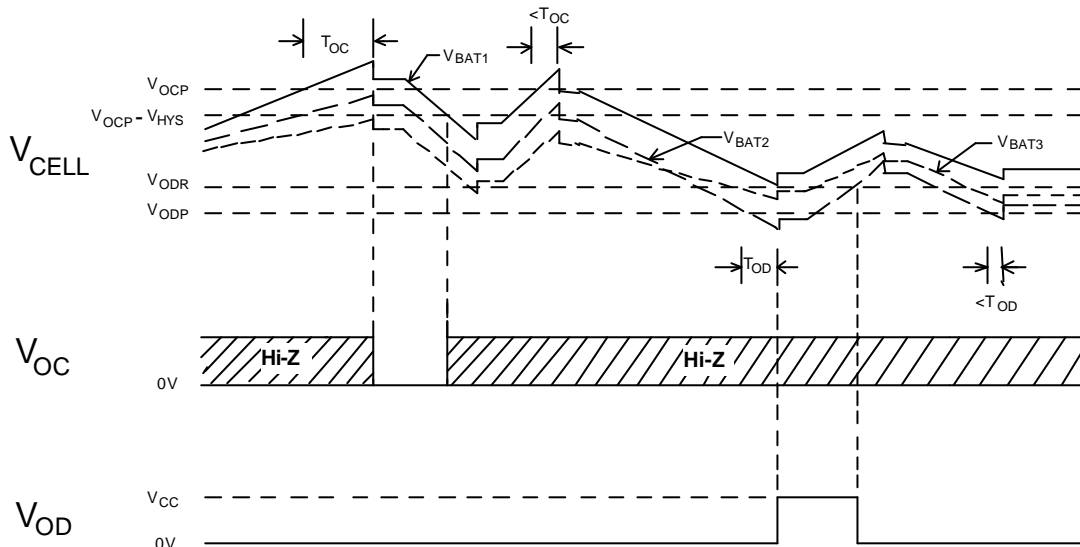
R5, R6, R7 and NPN transistor Q1 are used to switch the charge control MOSFET M2. If overcharge does not occur, no current flows into OC pin and Q1 is turned off, then M2 is turned on. When overcharge occurs, current flows into OC pin and Q1 is turned on, which turns off M2 in turn.

### Protection at CS Pin

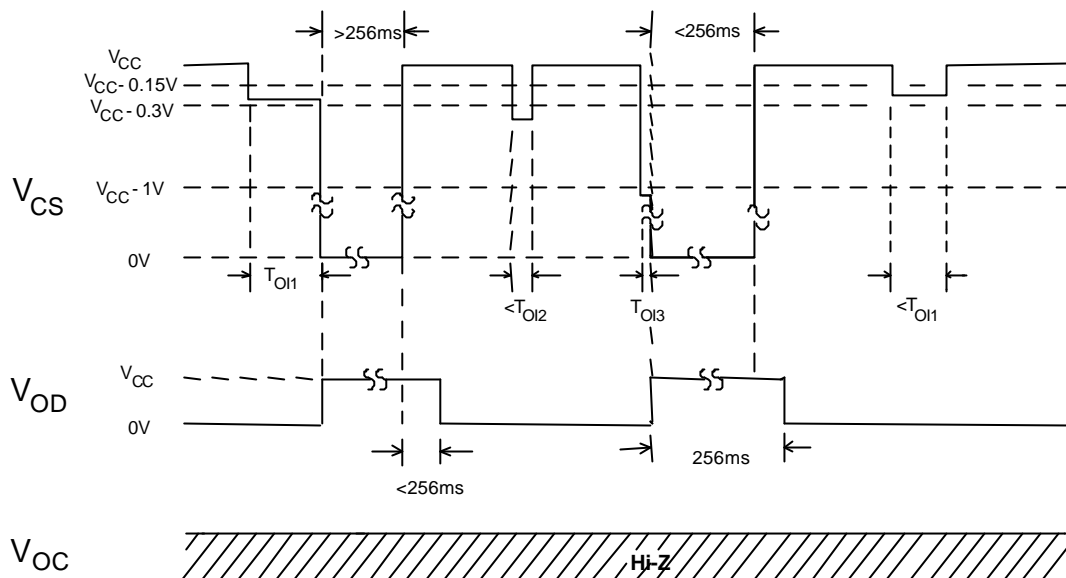
R8 is used for protection of IC when charger is connected in reverse. The charge detection function after overdischarge is possibly disabled by larger value of R8. Resistance of 1KΩ is recommended.

## TIMING DIAGRAM

### Overcharge and Overdischarge Protection ( $V_{CS}=V_{CC}$ )

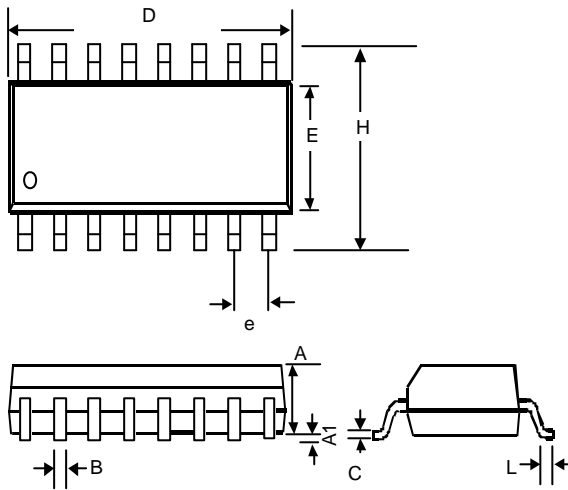


### Overcurrent Protection ( $V_{CELL}=3.5V$ )



**PHYSICAL DIMENSIONS**

- 16 LEAD PLASTIC SO (150 mil) (unit: mm)



SYMBOL	MIN	MAX
A	1.35	1.75
A1	0.10	0.25
B	0.33	0.51
C	0.19	0.25
D	9.80	10.00
E	3.80	4.00
e	1.27 (TYP)	
H	5.80	6.20
L	0.40	1.27